Diode Semiconductor Device - Page 1 of 1



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## Inclosure Material:

Glass

## **Overall Length:**

Between 0.230 inches and 0.300 inches

## **Terminal Length:**

Between 1.000 inches and 1.500 inches

## **Overall Diameter:**

Between 0.092 inches and 0.130 inches

### Mounting Method:

Terminal

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

5.9 regulator voltage, dc and 6.5 regulator voltage, dc

## Current Rating Per Characteristic:

7.50 milliamperes repetitive peak forward current

## **Power Rating Per Characteristic:**

250.0 milliwatts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

## **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## **Terminal Type And Quantity:**

2 uninsulated wire lead

## **Specification Data:**

81349-mil-s-19500/159 government specification

Shelf Life:

N/a

### Unit Of Measure:

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#### Demilitarization:

No

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